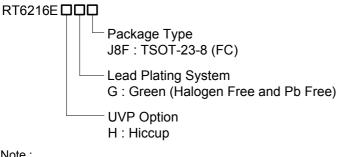
## **RT6216E**

## 2.5A, 24V, 500kHz, ACOT<sup>™</sup> Step-Down Converter

### **General Description**

The RT6216E is a high-efficiency, monolithic synchronous step-down DC-DC converter that can deliver up to 2.5A output current from a 4.5V to 24V input supply. The RT6216E adopts ACOT<sup>™</sup> architecture to allow the transient response to be improved and keep in constant frequency. Cycle-by-cycle current limit provides protection against shorted outputs and soft-start eliminates input current surge during start-up. Fault conditions also include output under voltage protection and thermal shutdown.

## **Ordering Information**



#### Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

## **Marking Information**

0W=DNN

0W= : Product Code DNN : Date Code

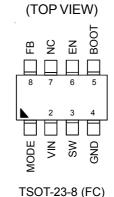
### **Features**

- Integrated 85mΩ /40mΩ MOSFETs
- 4.5V to 24V Supply Voltage Range
- 500kHz Switching Frequency
- ACOT<sup>™</sup> Control
- 0.791V ± 1.5% Voltage Reference
- Monotonic Start-Up into Pre-biased Outputs
- Output Adjustable from 0.791V to 6V
- Compact Package : TSOT-23-8 (FC)

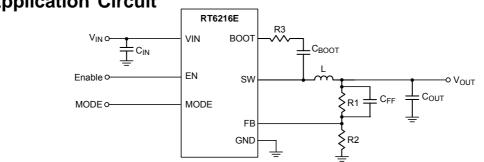
## Applications

- Set Top Box
- Portable TV
- Access Point Router
- DSL Modem
- LCDTV
- Notebook Systems and I/O Power
- Flat Panel Television and Monitors

## **Pin Configurations**



### **Simplified Application Circuit**

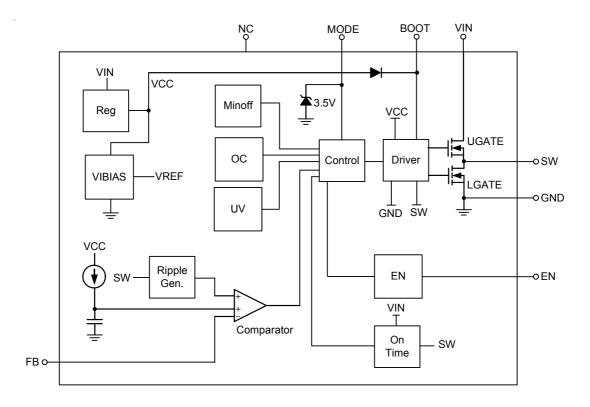




## **Functional Pin Description**

Pin No.	Pin Name	Pin Function
1	MODE	Mode Selection Input. Set MODE pin high will force RT6216E into CCM. Connect MODE to VIN with a $100k\Omega$ resistor for CCM application. Connect MODE pin to ground to force RT6216E into Pulse Skipping Mode for light load. Do not float MODE pin.
2	VIN	Input Voltage. Support 4.5V to 24V Input Voltage. Must bypass with a suitable large ceramic capacitor at this pin.
3	SW	Switch node. Connect to external L-C filter.
4	GND	System Ground.
5	воот	Bootstrap, supply for high side gate driver. Connect a $0.1\mu F$ ceramic capacitor between the BOOT and SW pins.
6	EN	Buck Enable. High = Enable.
7	NC	This pin is left floating.
8	FB	Feedback Input. The pin is used to set the output voltage of the converter to regulate to the desired via a resistive divider.

## **Function Block Diagram**



## Operation

The RT6216E is a high-efficiency, monolithic synchronous step-down DC-DC converter that can deliver up to 2.5A output current from a 4.5V to 24V input supply. Using the ACOT<sup>TM</sup> control mode can reduce the output capacitance and perform fast transient response. It can minimize the component size without additional external compensation network.

#### **Current Protection**

The inductor current is monitored via the internal switches cycle-by-cycle. Once the output voltage drops under UV threshold, the RT6216E will enter hiccup mode.

#### **Hiccup Mode**

The RT6216E use hiccup mode for UVP. When the protection function is triggered, the IC will shut down for a period of time and then attempt to recover automatically. Hiccup mode allows the circuit to operate safely with low input current and power dissipation, and then resume normal operation as soon as the overload or short circuit is removed.

#### Input Under-Voltage Lockout

To protect the chip from operating at insufficient supply voltage, the UVLO is needed. When the input voltage of VIN is lower than the UVLO falling threshold voltage, the device will be lockout.

### Shut-Down, Start-Up and Enable (EN)

The enable input (EN) has a logic-low level. When  $V_{EN}$  is below this level the IC enters shutdown mode. When  $V_{EN}$  exceeds its logic-high level the IC is fully operational.

### **External Bootstrap Capacitor**

Connect a  $0.1\mu$ F low ESR ceramic capacitor between BOOT and SW. This bootstrap capacitor provides the gate driver supply voltage for the high side N-channel MOSFET switch.

### **Over-Temperature Protection**

The RT6216E includes an Over-Temperature Protection (OTP) circuitry to prevent overheating due to excessive power dissipation. The OTP will shut down switching

operation when the junction temperature exceeds the OTP threshold value. Once the junction temperature cools down and is lower than the OTP lower threshold, the IC will resume normal operation.

#### **UVP Protection**

The RT6216E detects under-voltage conditions by monitoring the feedback voltage on FB pin. When the feedback voltage is lower than 50% of the target voltage, the UVP comparator will go high to turn off both internal high-side and low-side MOSFETs.



## Absolute Maximum Ratings (Note 1)

Supply Input Voltage, VIN	- –0.3V to 28V
EN Pin Voltage, EN	- –0.3V to 28V
Switch Voltage, SW	
SW (t ≤ 10ns)	5V to 30V
• BOOT to SW, V <sub>BOOT</sub> - V <sub>SW</sub>	–0.3V to 6V
BOOT Voltage	- –0.3V to 34V
Other Pins	- –0.3V to 6V
• Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
TSOT-23-8 (FC)	- 1.428W
Package Thermal Resistance (Note 2)	
TSOT-23-8 (FC), θ <sub>JA</sub>	- 70°C/W
TSOT-23-8 (FC), θ <sub>JC</sub>	- 15°C/W
Junction Temperature	- 150°C
Lead Temperature (Soldering, 10 sec.)	- 260°C
Storage Temperature Range	- –65°C to 150°C
ESD Susceptibility (Note 3)	
HBM (Human Body Model)	- 2kV

## Recommended Operating Conditions (Note 4)

Supply Input Voltage	- 4.5V to 24V
Junction Temperature Range	– –40°C to 125°C
Ambient Temperature Range	40°C to 85°C

## **Electrical Characteristics**

(V<sub>IN</sub> = 12V,  $T_A$  = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Supply Voltage							
VIN Supply Input Operating Voltage	Vin		4.5		24	V	
VIN Under-Voltage Lockout Threshold	V <sub>UVLO</sub>	V <sub>IN</sub> Rising	3.7	3.9	4.1	V	
VIN Under-Voltage Lockout Threshold-Hysteresis	$\Delta V_{UVLO}$			350		mV	
Supply Current		·					
Supply Current (Shutdown)	I <sub>SHDN</sub>	V <sub>EN</sub> = 0V			10	μA	
Supply Current (Quiescent)	lQ	V <sub>EN</sub> = 2V, V <sub>FB</sub> = 1V, V <sub>MODE</sub> = 0V (Not Switching)		150	250	μA	
Soft-Start							
Internal Soft-Start Period	tss	V <sub>FB</sub> from 0% to 100%		1500		μS	
Enable Voltage							
EN Rising Threshold	V <sub>ENH</sub>		1.2	1.4	1.6	V	
EN Hysteresis	$\Delta V_{\text{EN}}$		80	150	220	mV	

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Mode Input Voltage	•					
Mode Input High Voltage	V <sub>MODEH</sub>		2			V
Mode Input Low Voltage	VMODEL				0.4	V
Feedback Threshold Voltage						
Feedback Threshold Voltage	V <sub>FB</sub>		779	791	803	mV
Internal MOSFET	•	·				
High-Side Switch-On Resistance	RDS(ON)_H	VBOOT-VSW = 4.8V		85		mΩ
Low-Side Switch-On Resistance	R <sub>DS(ON)</sub> _L			40		mΩ
Current Limit		•	•			
Low-Side Switch Valley Current Limit	I <sub>LIM_L</sub>		2.7	3.2		А
High-Side Switch Peak Current Limit	ILIM_H			5.5		А
Switching Frequency						
Switching Frequency	f <sub>SW</sub>			500		kHz
On-Time Timer Control						
Maximum Duty Cycle	DMAX			90		%
Minimum On-Time	t <sub>ON</sub>			60		ns
Thermal Shutdown						
Thermal Shutdown	T <sub>SD</sub>			160		°C
Thermal Hysteresis	ΔTSD			25		°C
Output Under Voltage Protection	ns					
UVP Trip Threshold		UVP detect		50		%
		Hysteresis		10		%

Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

- Note 2.  $\theta_{JA}$  is measured at  $T_A = 25^{\circ}$ C on a high effective thermal conductivity four-layer test board per JEDEC 51-7. The first layer of copper area is filled.  $\theta_{JC}$  is measured at the lead of the package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.

## **Typical Application Circuit**

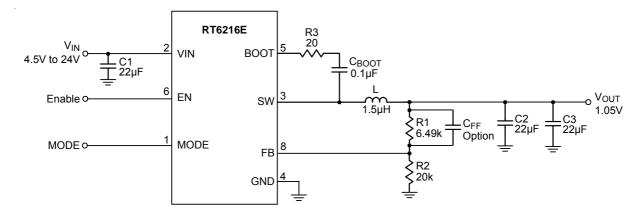


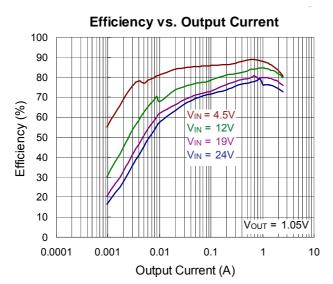
Table 1. Suggested Component Values

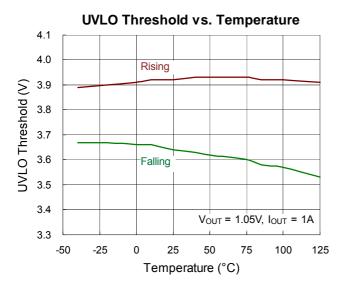
V <sub>оит</sub> (V)	<b>R1 (k</b> Ω)	<b>R2 (k</b> Ω)	<b>L (</b> μ <b>H)</b>	<b>C</b> ουτ (μ <b>F</b> )	C <sub>FF</sub> (pF)
1.05	6.49	20	1.5	44	
1.2	10.5	20	2.2	44	
1.8	25.5	20	2.2	44	
2.5	43.2	20	3.3	44	22 to 68
3.3	63.4	20	4.7	44	22 to 68
5	107	20	4.7	44	22 to 68

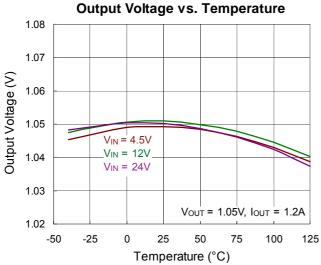
Note :

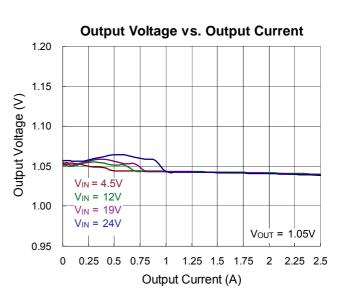
- (1) All the input and output capacitors are the suggested values, referring to the effective capacitances, subject to any de-rating effect, like a DC Bias.
- (2) For low output voltage application, it can optimize the load transient response of the device by adding feedforward capacitor (C<sub>FF</sub>, 22pF to 68pF).

## **Typical Operating Characteristics**

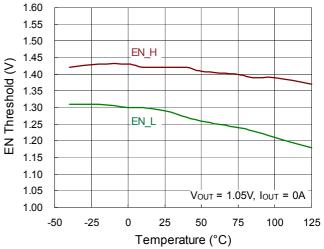


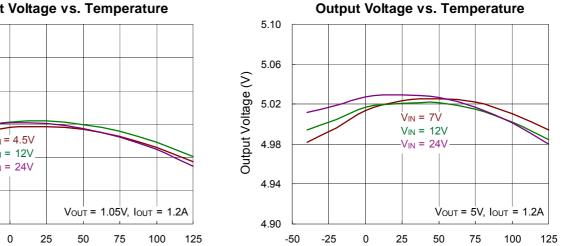






EN Threshold vs. Temperature



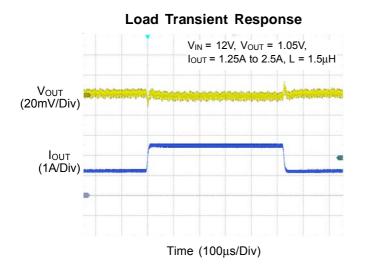


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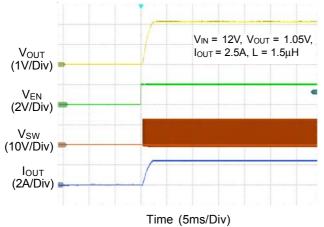
Temperature (°C)

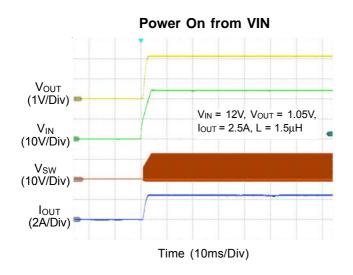
## RT6216E

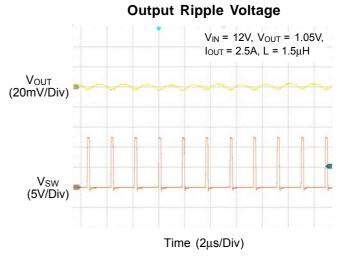




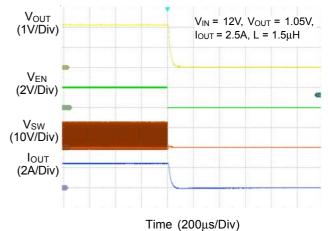
Power On from EN

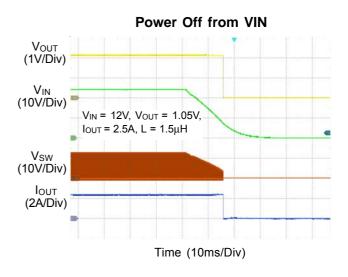






Power Off from EN





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## **Application Information**

#### **Inductor Selection**

The consideration of inductor selection includes inductance, RMS current rating and, saturation current rating. The inductance selection is generally flexible and is optimized for the low cost, low physical size, and high system performance.

Choosing lower inductance to reduce physical size and cost, and it is useful to improve the transient response. However, it causes the higher inductor peak current and output ripple voltage to decrease system efficiency. Conversely, higher inductance increase system efficiency, but the physical size of inductor will become larger and transient response will be slow because more transient time is required to change current (up or down) by inductor. A good compromise between size, efficiency, and transient response is to set a inductor ripple current ( $\Delta I_L$ ) about 20% to 50% of the desired full output load current.

Calculate the approximate inductance by the input voltage, output voltage, switching frequency ( $f_{SW}$ ), maximum rated output current ( $I_{OUT(MAX)}$ ) and inductor ripple current ( $\Delta I_L$ ).

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times \Delta I_{L}}$$

Once the inductance is chosen, the inductor ripple current  $(\Delta I_L)$  and peak inductor current can be calculated.

$$\Delta I_{L} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times L}$$
$$I_{L(PEAK)} = I_{OUT(MAX)} + \frac{1}{2} \Delta I_{L}$$
$$I_{L(VALLY)} = I_{OUT(MAX)} - \frac{1}{2} \Delta I_{L}$$

For the typical operating circuit design, the output voltage is 1.05V, maximum rated output current is 2.5A, input voltage is 12V, and inductor ripple current is 1.25A which is 50% of the maximum rated output current, the calculated inductance value is :

$$L = \frac{1.05 \times (12 - 1.05)}{12 \times 500 \times 10^3 \times 1.25} = 1.53 \mu H$$

The inductor ripple current set at 1.25A and so we select  $1.5\mu$ H inductance. The actual inductor ripple current and required peak current is shown as below :

$$\Delta I_{L} = \frac{1.05 \times (12 - 1.05)}{12 \times 500 \times 10^{3} \times 1.5 \times 10^{-6}} = 1.27A$$
$$I_{L(PEAK)} = I_{OUT(MAX)} + \frac{1}{2}\Delta I_{L} = 2.5 + \frac{1.27}{2} = 3.135A$$

Inductor saturation current should be chosen over IC's current limit.

#### Input Capacitor Selection

The input filter capacitors are needed to smooth out the RMS input ripple current drawn from the input power source and ripple voltage seen at the input of the converter. The voltage rating of the input filter capacitors must be greater than the maximum input voltage. It's also important to consider the ripple current capabilities of capacitors.

The RMS input ripple current ( $I_{RMS}$ ) is a function of the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), and rated output current ( $I_{OUT}$ ):

$$I_{RMS} = I_{OUT(MAX)} \times \frac{V_{OUT}}{V_{IN}} \sqrt{\frac{V_{IN}}{V_{OUT}} - 1}$$

The maximum RMS input ripple current occurs at maximum output load and it needs to be concerned about the ripple current capabilities of capacitors at maximum output load.

Ceramic capacitors are most often used because of their low cost, small size, high RMS current ratings, and robust surge current capabilities. It should pay attention that value of capacitors change as temperature, bias voltage, and operating frequency change. For example the capacitance value of a capacitor decreases as the dc bias across the capacitor increases.

However, take care when these capacitors are used at the input of circuits supplied by a wall adapter or other supply connected through long and thin wires. Current surges through the inductive wires can induce ringing at the IC's power input which could potentially cause large, damaging voltage spikes at VIN pin. If this phenomenon is observed, some bulk input capacitance may be

## RT6216E

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required. Ceramic capacitors can be placed in parallel with other types such as tantalum, electrolytic, or polymer to reduce voltage ringing and overshoot.

Choose capacitors rated at higher temperatures than required. Several ceramic capacitors may be paralleled to meet the RMS current, size, and height requirements of the application. The typical operating circuit use  $22\mu$ F and one  $0.1\mu$ F low ESR ceramic capacitors on the input.

#### **Output Capacitor Selection**

The RT6216E is optimized for output terminal with ceramic capacitors application and best performance will be obtained using them. The total output capacitance value is usually determined by the desired output ripple voltage level and transient response requirements for sag which is undershoot on positive load steps and soar which is overshoot on negative load steps.

#### **Output Ripple Voltage**

Output ripple voltage at the switching frequency is caused by the inductor current ripple and its effect on the output capacitor's ESR and stored charge. These two ripple components are called ESR ripple and capacitive ripple.

Since ceramic capacitors have extremely low ESR and relatively little capacitance, both components are similar in amplitude and both should be considered if ripple is critical.

 $V_{RIPPLE} = V_{RIPPLE(ESR)} + V_{RIPPLE(C)}$  $V_{RIPPLE(ESR)} = \Delta I_L \times R_{ESR}$  $V_{RIPPLE(C)} = \frac{\Delta I_L}{8 \times C_{OUT} \times f_{SW}}$ 

#### **Output Transient Undershoot and Overshoot**

In addition to output ripple voltage at the switching frequency, the output capacitor and its ESR also affect the voltage sag (undershoot) and soar (overshoot) when the load steps up and down abruptly. The ACOT<sup>TM</sup> transient response is very quick and output transients are usually small. However, the combination of small ceramic output capacitors (with little capacitance), low output voltages (with little stored charge in the output capacitors), and low duty cycle applications (which require high inductance to get reasonable ripple currents with high input voltages) increases the size of voltage variations in response to

very quick load changes. Typically, load changes occur slowly with respect to the IC's 500kHz switching frequency. But some modern digital loads can exhibit nearly instantaneous load changes and the following section shows how to calculate the worst-case voltage swings in response to very fast load steps.

The output voltage transient undershoot and overshoot each have two components : the voltage steps caused by the output capacitor's ESR, and the voltage sag and soar due to the finite output capacitance and the inductor current slew rate. Use the following formulas to check if the ESR is low enough (typically not a problem with ceramic capacitors) and the output capacitance is large enough to prevent excessive sag and soar on very fast load step edges, with the chosen inductor value.

The amplitude of the ESR step up or down is a function of the load step and the ESR of the output capacitor :

 $V_{ESR\_STEP} = \Delta I_{OUT} \times R_{ESR}$ 

The amplitude of the capacitive sag is a function of the load step, the output capacitor value, the inductor value, the input-to-output voltage differential, and the maximum duty cycle. The maximum duty cycle during a fast transient is a function of the on-time and the minimum off-time since the ACOT<sup>TM</sup> control scheme will ramp the current using on-times spaced apart with minimum off-times, which is as fast as allowed. Calculate the approximate on-time (neglecting parasitic) and maximum duty cycle for a given input and output voltage as :

$$t_{ON} = \frac{V_{OUT}}{V_{IN} \times f_{SW}}$$
 and  $D_{MAX} = \frac{t_{ON}}{t_{ON} + t_{OFF(MIN)}}$ 

The actual on-time will be slightly longer as the IC compensates for voltage drops in the circuit, but we can neglect both of these since the on-time increase compensates for the voltage losses. Calculate the output voltage sag as :

 $V_{SAG} = \frac{L \times (\Delta I_{OUT})^2}{2 \times C_{OUT} \times (V_{IN(MIN)} \times D_{MAX} - V_{OUT})}$ 

The amplitude of the capacitive soar is a function of the load step, the output capacitor value, the inductor value and the output voltage :

$$V_{\text{SOAR}} = \frac{L \times (\Delta \text{I}_{\text{OUT}})^2}{2 \times C_{\text{OUT}} \times V_{\text{OUT}}}$$

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## RT6216E

#### Feed-Forward Capacitor (C<sub>ff</sub>)

The RT6216E is optimized for ceramic output capacitors and for low duty cycle applications. However for high-output voltages, with high feedback attenuation, the circuit's transient response can be slowed. The high-output voltage circuits transient response could be improved by adding a small "feedforward" capacitor (C<sub>ff</sub>) across the upper FB divider resistor (Figure 1).Choose a suitable capacitor value that following suggested component BOM.

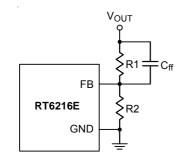


Figure 1. Cff Capacitor Setting

#### Enable Operation (EN)

There is an internal 1MEG resistor from EN to GND. For automatic start-up the high-voltage EN pin can be connected to VIN, through a 100k $\Omega$  resistor. Its large hysteresis band makes EN useful for simple delay and timing circuits. EN can be externally pulled to VIN by adding a resistor-capacitor delay (R<sub>EN</sub> and C<sub>EN</sub> in Figure 2). Calculate the delay time using EN's internal threshold where switching operation begins.

An external MOSFET can be added to implement digital control of EN when no system voltage above 2V is available (Figure 3). In this case, a  $100k\Omega$  pull-up resistor, R<sub>EN</sub>, is connected between VIN and the EN pin. MOSFET Q1 will be under logic control to pull down the EN pin. To prevent enabling circuit when VIN is smaller than the VOUT target value or some other desired voltage level, a resistive voltage divider can be placed between the input voltage and ground and connected to EN to create an additional input under voltage lockout threshold (Figure 4).

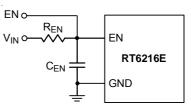


Figure 2. External Timing Control

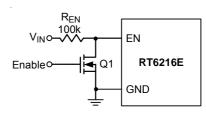


Figure 3. Digital Enable Control Circuit

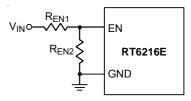


Figure 4. Resistor Divider for Lockout Threshold Setting

### **Output Voltage Setting**

Set the desired output voltage using a resistive divider from the output to ground with the midpoint connected to FB. The output voltage is set according to the following equation :

$$V_{OUT} = 0.791 V \times (1 + \frac{R1}{R2})$$

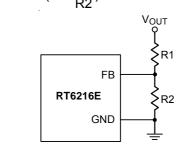


Figure 5. Output Voltage Setting

## **RT6216E**

Place the FB resistors within 5mm of the FB pin. To minimize power consumption without excessive noise pick-up, considering typical application, fix R2 =  $20k\Omega$ and calculate R1 as follows :

$$R1 = \frac{R2 \times (V_{OUT} - V_{REF})}{V_{REF}}$$

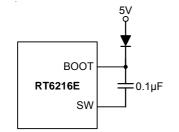
For output voltage accuracy, use divider resistors with 1% or better tolerance.

### **External BOOT Bootstrap Diode**

When the input voltage is lower than 5.5V it is recommended to add an external bootstrap diode between VIN and the BOOT pin to improve enhancement of the internal MOSFET switch and improve efficiency. The bootstrap diode can be a low cost one such as 1N4148 or BAT54.

#### **External BOOT Capacitor Series Resistance**

The internal power MOSFET switch gate driver is optimized to turn the switch on fast enough for low power loss and good efficiency, but also slow enough to reduce EMI. Switch turn-on is when most EMI occurs since V<sub>SW</sub> rises rapidly. During switch turn-off, SW is discharged relatively slowly by the inductor current during the dead time between high-side and low-side switch on-times. In some cases it is desirable to reduce EMI further, at the expense of some additional power dissipation. The switch turn-on can be slowed by placing a small (<47 $\Omega$ ) resistance between BOOT and the external bootstrap capacitor. This will slow the high-side switch turn-on and V<sub>SW</sub>'s rise. To remove the resistor from the capacitor charging path (avoiding poor enhancement due to undercharging the BOOT capacitor), use the external diode shown in Figure 6 to charge the BOOT capacitor and place the resistance between BOOT and the capacitor/diode connection.



#### Mode Selection setting

The RT6216E has MODE Selection function to set Pulse Skipping Mode for light load. To connect MODE pin to ground to force RT6216E into Pulse Skipping Mode for light load efficiency improvement. Pulling the MODE pin high (i.e. > 2V) will force RT6216E into CCM. In order to avoid the abnormal operation caused by noise, MODE pin can't be floated.

#### **Thermal Considerations**

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

#### $P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance,  $\theta_{JA}$ , is layout dependent. For TSOT-23-8 (FC) package, the thermal resistance,  $\theta_{JA}$ , is 70°C/W on a standard four-layer thermal test board. The maximum power dissipation at  $T_A = 25^{\circ}C$  can be calculated by the following formula :

 $P_{D(MAX)}$  = (125°C - 25°C) / (70°C/W) = 1.428W for TSOT-23-8 (FC) package

The maximum power dissipation depends on the operating ambient temperature for fixed  $T_{J(MAX)}$  and thermal resistance,  $\theta_{JA}$ . The derating curve in Figure 7 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

Figure 6. External Bootstrap Diode

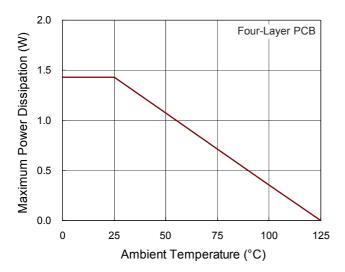
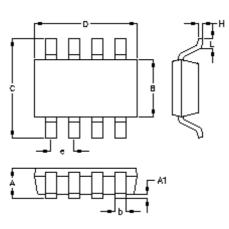


Figure 7. Derating Curve of Maximum Power Dissipation



### **Outline Dimension**



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	0.700	1.000	0.028	0.039	
A1	0.000	0.100	0.000	0.004	
В	1.397	1.803	0.055	0.071	
b	0.220	0.380	0.009	0.015	
С	2.591	3.000	0.102	0.118	
D	2.692	3.099	0.106	0.122	
е	0.585	0.715	0.023	0.028	
Н	0.080	0.254	0.003	0.010	
L	0.300	0.610	0.012	0.024	

TSOT-23-8 (FC) Surface Mount Package

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